

# AN5290 Application note

## Getting started with STM32WB MCU hardware development

#### Introduction

The microcontrollers of the STM32WB series are designed to minimize the number of external components needed to ensure optimized RF performance.

This document details the bill of materials (BOM) for Bluetooth® Low-Energy applications.

The QFN48 package is used as a reference, but the considerations valid for it can be easily extended to other packages.

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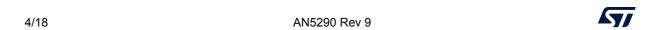
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#### 1 Design considerations

#### 1.1 SMPS and LDO configurations

The STM32WB series microcontrollers are based on Arm<sup>®</sup>(a) cores.

The power management implemented on some of these devices (refer to the datasheets) embeds a powerful switched-mode power supply (SMPS) to improve power efficiency when the supply voltage is higher than 2 V (otherwise, the LDO configuration is used). The two configurations are shown in *Figure 1*. See AN5246 "How to use SMPS to improve power efficiency on STM32WB MCUs", available on www.st.com, for more details.

 $V_{DD}$ VDDSMPS VDDSMPS **SMPS SMPS** VLXSMPS SMPS mode or VLXSMPS (not used) BYPASS mode LPR **LPR** VFBSMPS VFBSMPS **RFR RFR** MR MR SMPS configuration LDO configuration MS41409V4

Figure 1. Supply configurations

To operate properly, the SMPS needs two inductors and two capacitors. In the LDO configuration, no external components are needed. The detailed electrical schemes are shown in *Section 2*.

arm

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#### 1.2 LDO configuration for $V_{DD} > 2.5 \text{ V}$

This configuration applies only to STM32WB5xxx and STM32WB3xxx devices with REV\_ID = 0x2001 in register DBGMCU\_IDCODE (see RM0434, available on www.st.com).

An inductance and a resistor must be added in series between VLXSMPS and VFBSMPS pins, as shown in *Figure 2*.

VDDSMPS

VLXSMPS

SMPS

(not used)

VFBSMPS

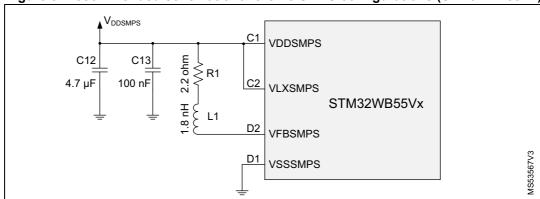
Main RF regulator regulator regulator

Figure 2. LDO configuration

The recommended values (see Figure 3) are:

- Inductance: 1.8 ± 0.1 nH, 6 GHz ± 15% self-resonance frequency, 1000 mA rated current (for example, Murata LQG15HS1N8B02)
- Resistor: 2.2 Ω, able to support 1 W for 5 ns (for example, Vishay D10/CRCW0402e3)

Figure 3. Recommended schematic for the no SMPS configurations (STM32WB55Vx)



#### 1.3 HSE trimming

STM32WB MCUs use the HSE oscillator for the RF clock generation, this component must be fine-tuned. Internal load capacitors are used, removing the need for external parts, as shown in *Figure 4*. See AN5042 "How to calibrate the HSE clock for RF applications on STM32 wireless MCUs", available on www.st.com, for more details.

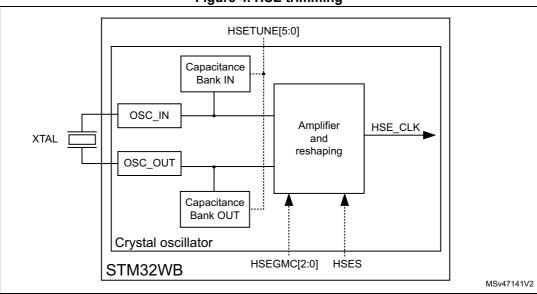


Figure 4. HSE trimming

#### 1.4 RF matching

There is a unique pin RX/TX for the RF, and this interface is single-ended, eliminating the need for external baluns. Furthermore, internal band prefiltering helps to reduce external components.

An external PI filter made up by discrete components is needed for impedance matching, it is followed by a ceramic filter for rejection of harmonics. Another matching network is required for the antenna. To optimize the BOM and the performance stability, these filters can be replaced by an integrated passive device (IPD), as shown in *Figure 5*.

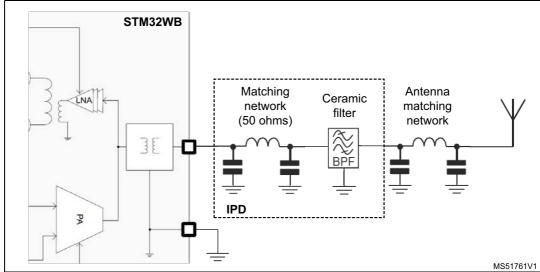


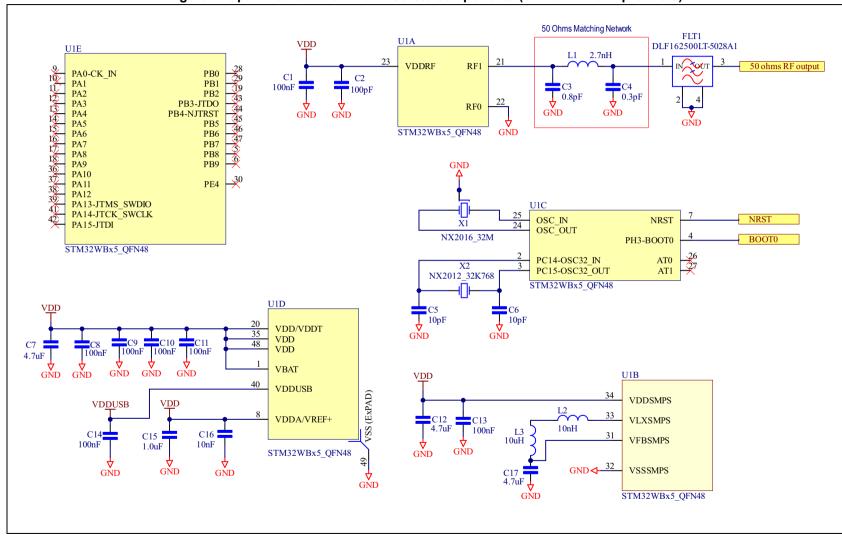
Figure 5. RF matching and external filters

The RF performance strongly depends upon the PCB layout. AN5165 "How to *develop RF hardware using STM32WB microcontrollers*", available on *www.st.com*, describes the precautions needed for the layout of an RF board with the STM32WB.

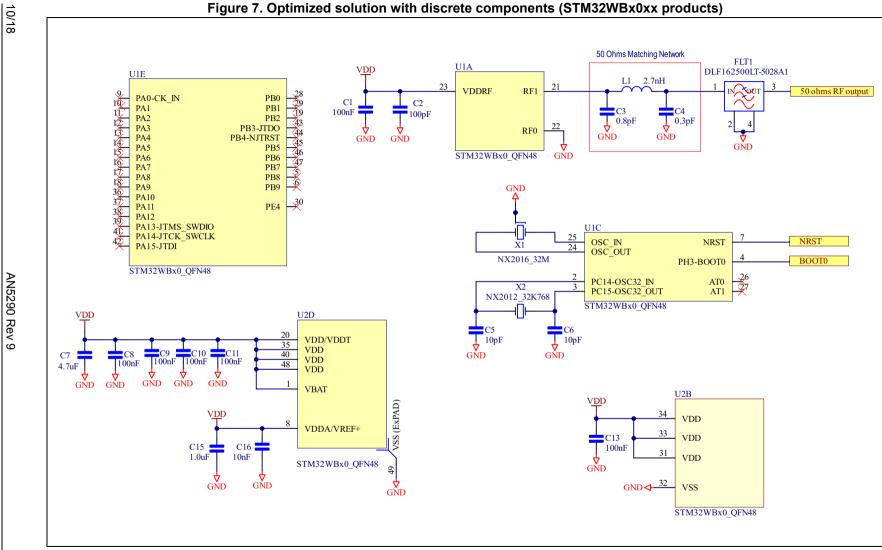
**Schematics** 



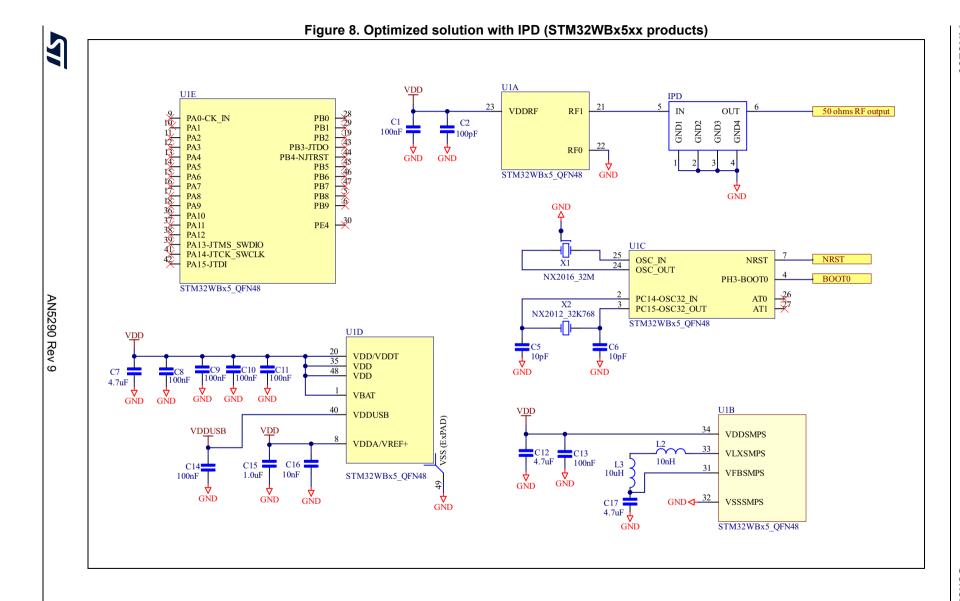
Figure 6. Optimized solution with discrete components (STM32WBx5xx products)

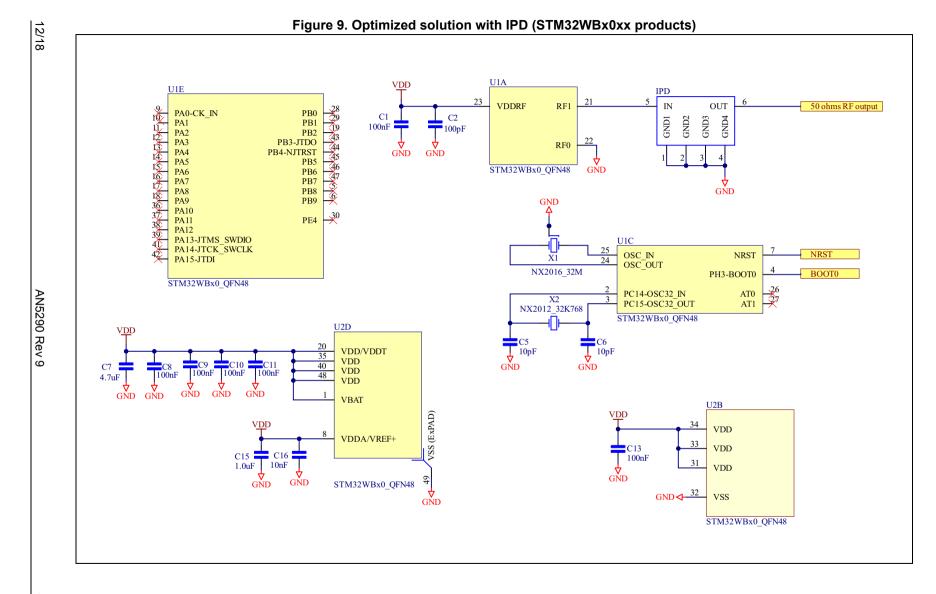


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**Schematics** 







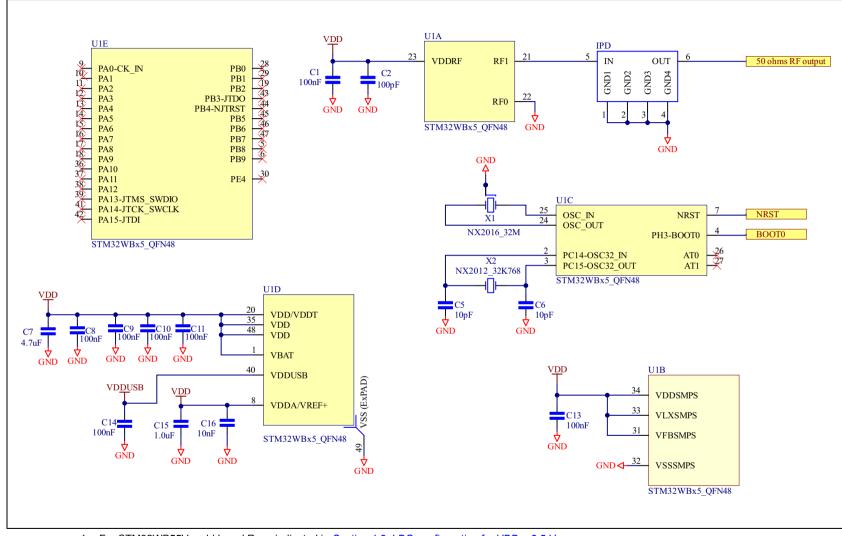


Figure 10. Solution without SMPS (STM32WBx5xx products)

1. For STM32WB55Vx add L and R, as indicated in Section 1.2: LDO configuration for VDD > 2.5 V.

Bill of materials AN5290

#### 3 Bill of materials

Table 1. Bill of materials - Optimized solution with discrete components

Designator	Description	Comment	Footprint	Manufacturer	Part number
C16	Capacitor, not	10 nF decoupling capacitor		Kyocera-AVX	0402YD103KAT2A
C1, C8, C9, C10, C11, C13, C14	polarized (X5R)	100 nF decoupling capacitors		Murata	GRM155R61H104KE19D
C2	Capacitor, not polarized (X7R)	100 pF decoupling capacitor		Yageo	CC0402KRX7R9BB101
C5, C6	Capacitor, not polarized (C0G)	10 pF LSE crystal capacitor	0402		GRM0335C1E100JA01D
C7, C12	Capacitor, not	4.7 µF decoupling capacitors		Murata	GRM155R61A475MEAAD
C15	polarized (X5R)	1.0 µF decoupling capacitor			GRM155R61A105KE15D
C3	Capacitor, not	0.8 pF matching network			GRM1555C1HR80BA01D
C4	polarized (C0G)	0.3 pF matching network			GRM1555C1HR30WA01D
L3		10 µH SMPS inductor	0805		LQM21FN100M70L
L2	Inductor	10 nH SMPS inductor	0402	Murata	LQG15WZ10NJ02D
L1		2.7 nH matching network	0402		LQG15HS2N7S02D
X1	Constal	32 MHz - HSE	NX2016	NDK	NX2016SA_32MHz
X2	Crystal	32.768 kHz - LSE	NX2012		NX2012SA_32-768kHz
FLT1	Low-pass filter	Harmonics rejection	-	Murata	DLF162500LT-5028A1

AN5290 Bill of materials

Table 2. Bill of materials- Optimized solution with IPD

Designator	Description	Comment	Footprint	Manufacturer	Part number
C16	Capacitor, not	10 nF decoupling capacitor		Kyocera-AVX	0402YD103KAT2A
C1, C8, C9, C10, C11, C13, C14	polarized (X5R)	100 nF decoupling capacitors	0402	Murata	GRM155R61H104KE19D
C2	Capacitor, not	100 pF decoupling capacitors		Yageo	CC0402KRX7R9BB101
C5, C6	polarized	10 pF LSE crystal capacitor		Murata	GRM0335C1E100JA01D
C7, C12	Capacitor, not polarized (X5R)	4.7 μF decoupling capacitor		Murata	GRM155R61A475MEAAD
C15		1.0 µF decoupling capacitor			GRM155R61A105KE15D
L2	Inductor	10 nH SMPS inductor	0402	Murata	LQG15WZ10NJ02D
L3		10 μH SMPS inductor	0805		LQM21FN100M70L
X1	Crystal	32 MHz - HSE	NX2016	- NDK	NX2016SA_32MHz
X2		32.768 kHz - LSE	NX2012		NX2012SA_32-768kHz
FLT1	Low-pass filter	Matching network and low-pass filter	Bumpless CSP	STMicroelectronics	MLPF-WB55-01E3

Table 3. Bill of materials - Solution without SMPS

Designator	Description	Comment	Footprint	Manufacturer	Part number
C16	Capacitor, not polarized (X5R)	10 nF decoupling capacitor	0402	Kyocera-AVX	0402YD103KAT2A
C1, C8, C9, C10, C11, C13, C14		100 nF decoupling capacitors		Murata	GRM155R61H104KE19D
C2	Capacitor, not	100 pF decoupling capacitor		Yageo	CC0402KRX7R9BB101
C5, C6	polarized	10 pF LSE crystal capacitors		Murata	GRM0335C1E100JA01D
C7	Capacitor, not polarized (X5R)	4.7 μF decoupling capacitor		Murata	GRM155R61A475MEAAD
C15		1.0 μF decoupling capacitor			GRM155R61A105KE15D
X1	Crystal	32 MHz - HSE	NX2016	NDK	NX2016SA_32MHz
X2		32.768 kHz - LSE	NX2012	NDK	NX2012SA_32-768kHz
FLT1	Low-pass filter	Matching network and low-pass filter	Bumpless CSP	STMicroelectronics	MLPF-WB55-01E3

Conclusion AN5290

## 4 Conclusion

The devices of the STM32WB series show excellent RF performance (detailed in the product datasheets available on <a href="https://www.st.com">www.st.com</a>), with a minimal set of external components associated with a PCB layout that complies with RF guidelines.

AN5290 Revision history

## 5 Revision history

**Table 4. Document revision history** 

Date	Revision	Changes	
14-Feb-2019	1	Initial release.	
20-Feb-2019	2	Updated Section 1.1: SMPS and LDO configurations. Updated Table 2: Bill of materials- Optimized solution with IPD.	
25-Sep-2019	3	Updated Section 1.1: SMPS and LDO configurations and Section 4: Conclusion.  Updated Figure 4: HSE trimming, Figure 6: Optimized solution with discrete components (STM32WBx5xx products), Figure 8: Optimized solution with IPD (STM32WBx5xx products) and Figure 10: Solution without SMPS (STM32WBx5xx products).  Added Figure 7: Optimized solution with discrete components (STM32WBx0xx products) and Figure 9: Optimized solution with IPD (STM32WBx0xx products).	
22-Jan-2020	4	Updated Table 1: Bill of materials - Optimized solution with discrete components, Table 2: Bill of materials- Optimized solution with IPD and Table 3: Bill of materials - Solution without SMPS.  Updated Figure 6: Optimized solution with discrete components (STM32WBx5xx products), Figure 7: Optimized solution with discrete components (STM32WBx0xx products), Figure 8: Optimized solution with IPD (STM32WBx5xx products), Figure 9: Optimized solution with IPD (STM32WBx0xx products) and Figure 10: Solution without SMPS (STM32WBx5xx products).	
12-May-2020	5	Updated Figure 1: Supply configurations. Added Section 1.2: LDO configuration for VDD > 2.5 V.	
22-Jul-2020	6	Updated Section 1.2: LDO configuration for VDD > 2.5 V. Updated Figure 3: Recommended schematic for the no SMPS configurations (STM32WB55Vx). Added footnote to Figure 10: Solution without SMPS (STM32WBx5xx products).	
30-Mar-2023	7	Updated Section 1.2: LDO configuration for VDD > 2.5 V.  Updated schematics (figures 6 to 10).  Updated Table 1: Bill of materials - Optimized solution with discrete components, Table 2: Bill of materials- Optimized solution with IPD, and Table 3: Bill of materials - Solution without SMPS.  Minor text edits across the whole document.	
08-Jan-2024	8	Updated Figure 3: Recommended schematic for the no SMPS configurations (STM32WB55Vx).	
25-Nov-2024	9	Updated Section 1.4: RF matching.  Updated Figure 8: Optimized solution with IPD (STM32WBx5xx products), Figure 9: Optimized solution with IPD (STM32WBx0xx products), and Figure 10: Solution without SMPS (STM32WBx5xx products).	



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